Diode Semiconductor Device - Page 1 of 1



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| Incl | osure Material: |
|-------|--|
| Gla | SS |
| Ονε | erall Length: |
| 0.35 | 50 inches |
| Ter | minal Length: |
| 1.00 | 00 inches |
| Ονε | erall Diameter: |
| 0.14 | 15 inches |
| Fun | ction For Which Designed: |
| Zen | er diode |
| Μοι | unting Method: |
| Terr | ninal |
| Fea | tures Provided: |
| Her | metically sealed case |
| Sen | niconductor Material: |
| Silic | zon |
| Vol | age Rating In Volts Per Characteristic: |
| 8.7 | regulator voltage |
| Vol | tage Tolerance In Percent: |
| -5.0 | to 5.0 |
| Cur | rent Rating Per Characteristic: |
| 150 | .00 milliamperes voltage regulator diode current |
| Pov | ver Rating Per Characteristic: |
| 5.0 | watts total device dissipation |
| Max | ximum Operating Tempurature Per Measurement Point: |
| 200 | .0 degrees celsius ambient air |
| Ter | minal Type And Quantity: |
| 2 ur | ninsulated wire lead |
| Spe | cification Data: |
| 801 | 31-release 5750 government specification |
| She | If Life: |
| N/a | |
| Uni | t Of Measure: |
| | |
| Den | nilitarization: |
| No | |
| Fiig | : |
| | 0a0 |